



BYC10DX-600

Hyperfast power diode

Rev. 1 — 30 June 2011

Product data sheet

1. Product profile

1.1 General description

Hyperfast power diode in a SOD113 (2-lead TO-220F) plastic package.

1.2 Features and benefits

- Isolated plastic package
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

1.3 Applications

- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

1.4 Quick reference data

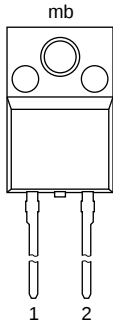
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; δ = 0.5 ; T _h = 41 °C; see Figure 1 ; see Figure 2	-	-	10	A
Static characteristics						
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; see Figure 5	-	2	2.5	V
		I _F = 10 A; T _j = 150 °C; see Figure 5	-	1.4	1.8	V
Dynamic characteristics						
t _{rr}	reverse recovery time	I _F = 10 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 25 °C; see Figure 6	-	18	-	ns



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	n.c.	mounting base; isolated		
SOD113 (TO-220F)				

3. Ordering information

Table 3. Ordering information

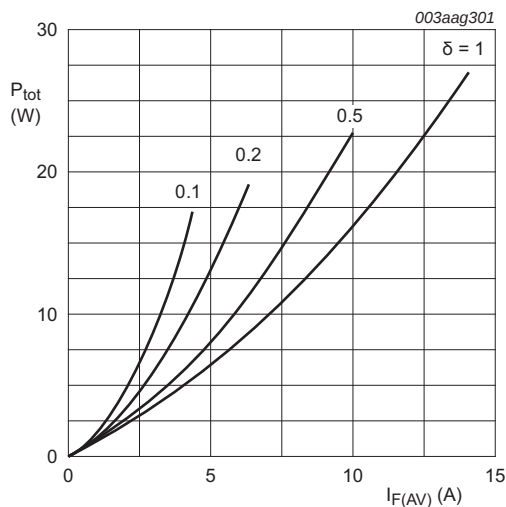
Type number	Package		
	Name	Description	Version
BYC10DX-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

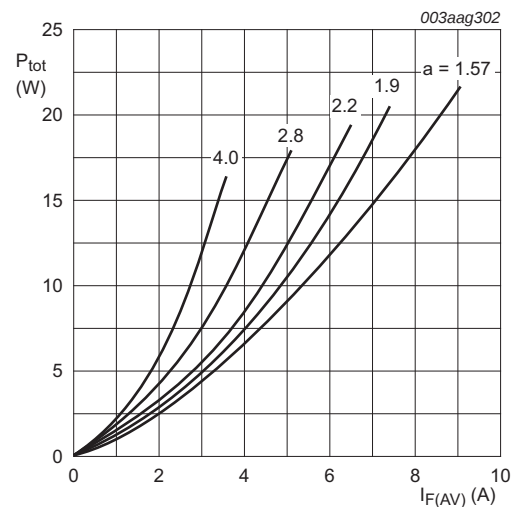
Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	DC	-	500	V
$I_{F(AV)}$	average forward current	square-wave pulse; $\delta = 0.5$; $T_h = 41^\circ\text{C}$; see Figure 1 ; see Figure 2	-	10	A
I_{FRM}	repetitive peak forward current	square-wave pulse; $\delta = 0.5$; $t_p = 25\ \mu\text{s}$; $T_h = 41^\circ\text{C}$	-	20	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10\ \text{ms}$; sine-wave pulse; $T_{j(\text{init})} = 25^\circ\text{C}$; see Figure 3	-	65	A
		$t_p = 8.3\ \text{ms}$; sine-wave pulse; $T_{j(\text{init})} = 25^\circ\text{C}$; see Figure 3	-	71	A
T_{stg}	storage temperature		-40	150	$^\circ\text{C}$
T_j	junction temperature		-	150	$^\circ\text{C}$



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 0.987\ \text{V}; R_s = 0.065\ \Omega$$

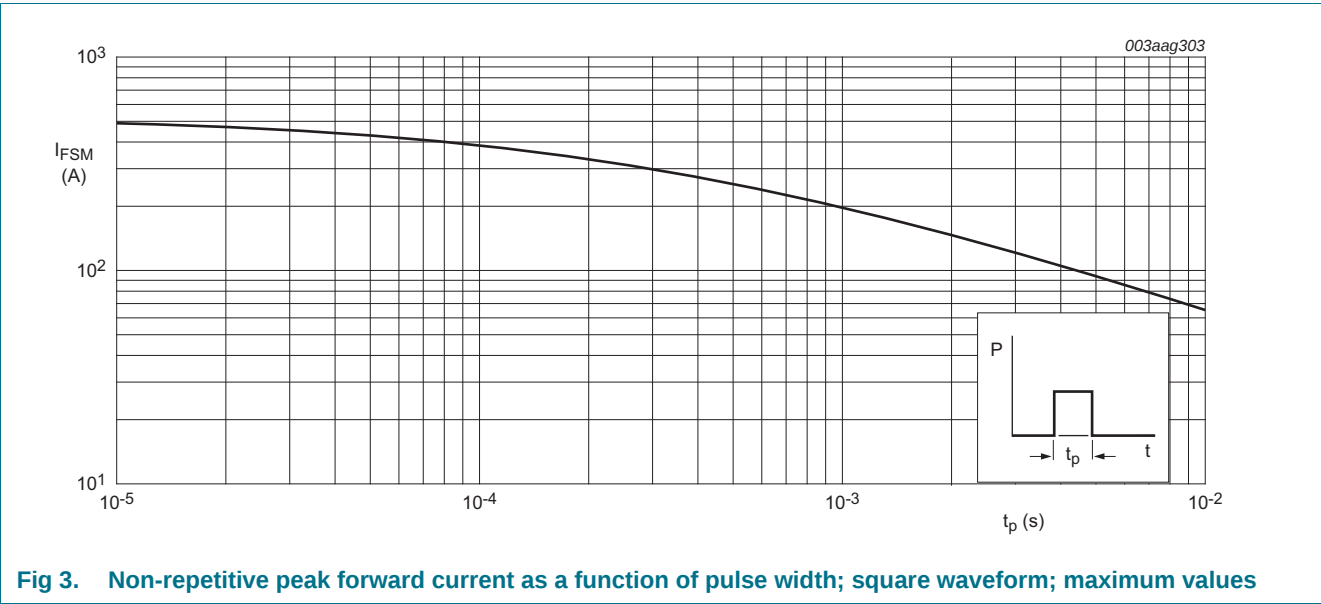
Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

$$V_o = 0.987\ \text{V}; R_s = 0.065\ \Omega$$

Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values



5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	without heatsink compound	-	-	5.9	K/W
		with heatsink compound ; see Figure 4	-	-	4.8	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air		-	60	-	K/W

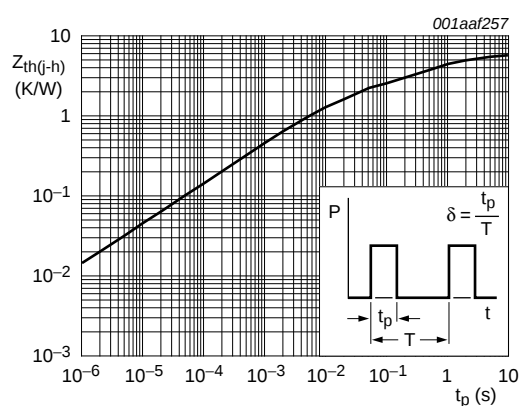


Fig 4. Transient thermal impedance from junction to heatsink as a function of pulse width

6. Isolation characteristics

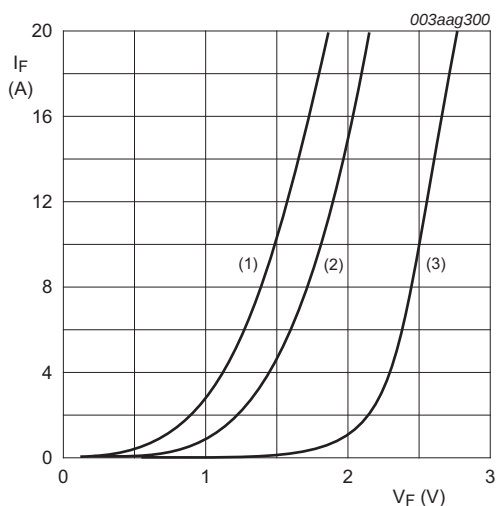
Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50 Hz $\leq f \leq$ 60 Hz; RH $\leq$ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C_{isol}	isolation capacitance	f = 1 MHz ; from cathode to external heatsink	-	10	-	pF

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; see Figure 5	-	2	2.5	V
		I _F = 10 A; T _j = 150 °C; see Figure 5	-	1.4	1.8	V
		I _F = 20 A; T _j = 150 °C; see Figure 5	-	1.7	2.2	V
I _R	reverse current	V _R = 500 V; T _j = 100 °C	-	1.1	3	mA
		V _R = 600 V	-	9	200	μA
Dynamic characteristics						
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 50 A/μs; T _j = 25 °C; see Figure 6	-	15	30	ns
		I _F = 10 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 25 °C; see Figure 6	-	18	-	ns
I _{RM}	peak reverse recovery current	I _F = 10 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 100 °C; see Figure 6	-	9.5	12	A
		I _F = 10 A; V _R = 400 V; dI _F /dt = 50 A/μs; T _j = 125 °C; see Figure 6	-	3	7.5	A
V _{FR}	forward recovery voltage	I _F = 10 A; dI _F /dt = 100 A/μs; T _j = 25 °C; see Figure 7	-	8	11	V



- (1) $T_j = 150\text{ °C}$; typical values;
 (2) $T_j = 150\text{ °C}$; maximum values;
 (3) $T_j = 25\text{ °C}$; maximum values;
 $V_o = 0.987\text{ V}$; $R_s = 0.065\text{ }\Omega$

Fig 5. Forward current as a function of forward voltage

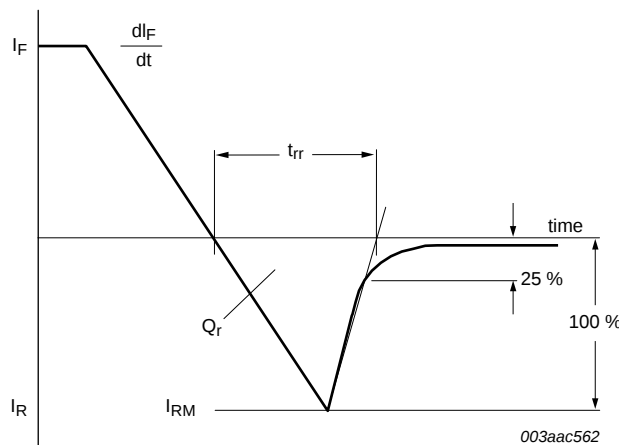


Fig 6. Reverse recovery definitions; ramp recovery

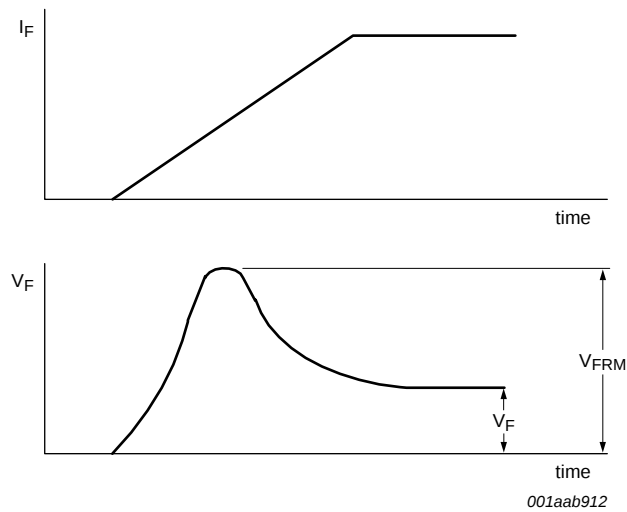


Fig 7. Forward recovery definitions

8. Package outline

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 2-lead TO-220 'full pack'

SOD113

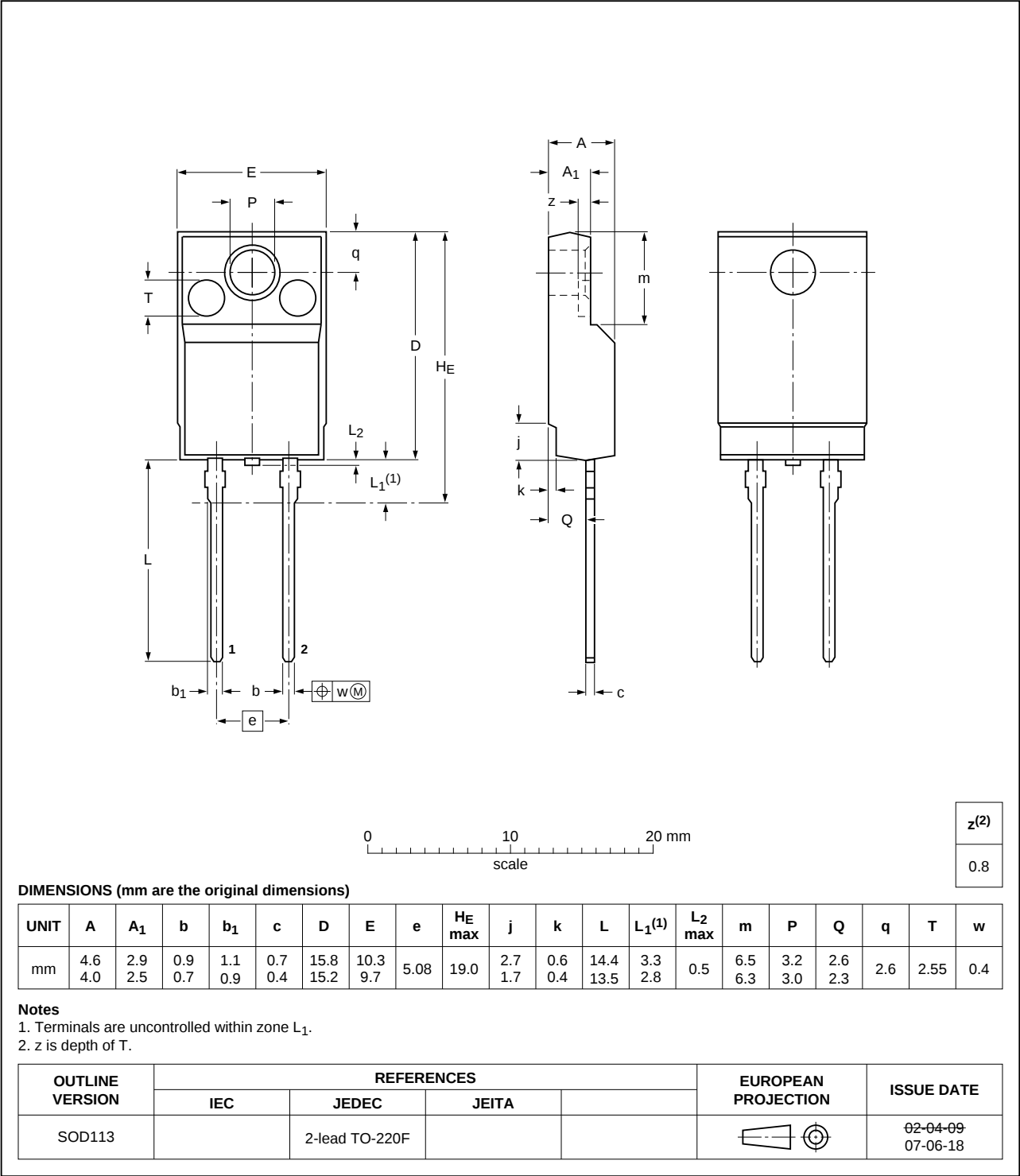


Fig 8. Package outline SOD113 (TO-220F)

9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYC10DX-600 v.1	20110630	Product data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status ^[1] ^[2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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